

### FEATURES

- Double Side Cooling
- High Surge Capability

### APPLICATIONS

- High Power Drives
- High Voltage Power Supplies
- DC Motor Control
- Welding
- Battery Chargers

### VOLTAGE RATINGS

Type Number	Repetitive Peak Voltages $V_{DRM}$ $V_{RRM}$	Conditions
DCR820SG65	6500	$T_{vj} = 0^\circ \text{ to } 125^\circ \text{ C,}$ $I_{DRM} = I_{RRM} = 50\text{mA,}$ $V_{DRM}, V_{RRM} t_p = 10\text{ms,}$ $V_{DSM} \text{ \& } V_{RSM} =$ $V_{DRM} \text{ \& } V_{RRM} + 100\text{V}$ Respectively
DCR820SG64	6400	
DCR820SG63	6300	
DCR820SG62	6200	
DCR820SG61	6100	
DCR820SG60	6000	

Lower voltage grades available.

### ORDERING INFORMATION

When ordering, select the required part number shown in the Voltage Ratings selection table.

For example:

#### DCR820SG62

Note: Please use the complete part number when ordering and quote this number in any future correspondence relating to your order.

### KEY PARAMETERS

$V_{DRM}$	6500V
$I_{T(AV)}$	387A
$I_{TSM}$	6000A
dV/dt*	1000V/ $\mu\text{s}$
dI/dt	100A/ $\mu\text{s}$

\*Higher dV/dt selections available

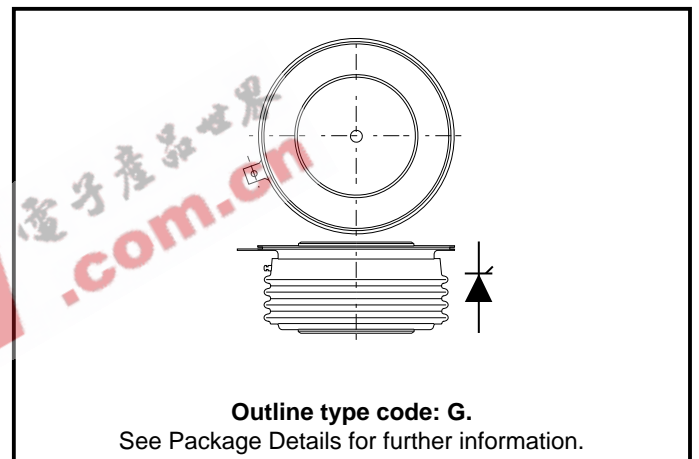


Fig. 1 Package outline

## CURRENT RATINGS

$T_{case} = 60^{\circ}\text{C}$  unless stated otherwise

Symbol	Parameter	Conditions	Max.	Units
<b>Double Side Cooled</b>				
$I_{T(AV)}$	Mean on-state current	Half wave resistive load	387	A
$I_{T(RMS)}$	RMS value	-	608	A
$I_T$	Continuous (direct) on-state current	-	567	A
<b>Single Side Cooled (Anode side)</b>				
$I_{T(AV)}$	Mean on-state current	Half wave resistive load	260	A
$I_{T(RMS)}$	RMS value	-	408	A
$I_T$	Continuous (direct) on-state current	-	357	A

## CURRENT RATINGS

$T_{case} = 80^{\circ}\text{C}$  unless stated otherwise

Symbol	Parameter	Conditions	Max.	Units
<b>Double Side Cooled</b>				
$I_{T(AV)}$	Mean on-state current	Half wave resistive load	310	A
$I_{T(RMS)}$	RMS value	-	485	A
$I_T$	Continuous (direct) on-state current	-	447	A
<b>Single Side Cooled (Anode side)</b>				
$I_{T(AV)}$	Mean on-state current	Half wave resistive load	204	A
$I_{T(RMS)}$	RMS value	-	321	A
$I_T$	Continuous (direct) on-state current	-	279	A

**SURGE RATINGS**

Symbol	Parameter	Conditions	Max.	Units
$I_{TSM}$	Surge (non-repetitive) on-state current	10ms half sine; $T_{case} = 125^{\circ}C$	4.8	kA
$I^2t$	$I^2t$ for fusing	$V_R = 50\% V_{RRM}$ - 1/4 sine	$115 \times 10^3$	A <sup>2</sup> s
$I_{TSM}$	Surge (non-repetitive) on-state current	10ms half sine; $T_{case} = 125^{\circ}C$	6.0	kA
$I^2t$	$I^2t$ for fusing	$V_R = 0$	$180 \times 10^3$	A <sup>2</sup> s

**THERMAL AND MECHANICAL DATA**

Symbol	Parameter	Conditions	Min.	Max.	Units	
$R_{th(j-c)}$	Thermal resistance - junction to case	Double side cooled	dc	-	0.032	$^{\circ}C/W$
		Single side cooled	Anode dc	-	0.064	$^{\circ}C/W$
			Cathode dc	-	0.064	$^{\circ}C/W$
$R_{th(c-h)}$	Thermal resistance - case to heatsink	Clamping force 12.0kN with mounting compound	Double side	-	0.008	$^{\circ}C/W$
			Single side	-	0.016	$^{\circ}C/W$
$T_{vj}$	Virtual junction temperature	On-state (conducting)		-	135	$^{\circ}C$
		Reverse (blocking)		-	125	$^{\circ}C$
$T_{stg}$	Storage temperature range			-55	150	$^{\circ}C$
-	Clamping force			10.8	13.2	kN

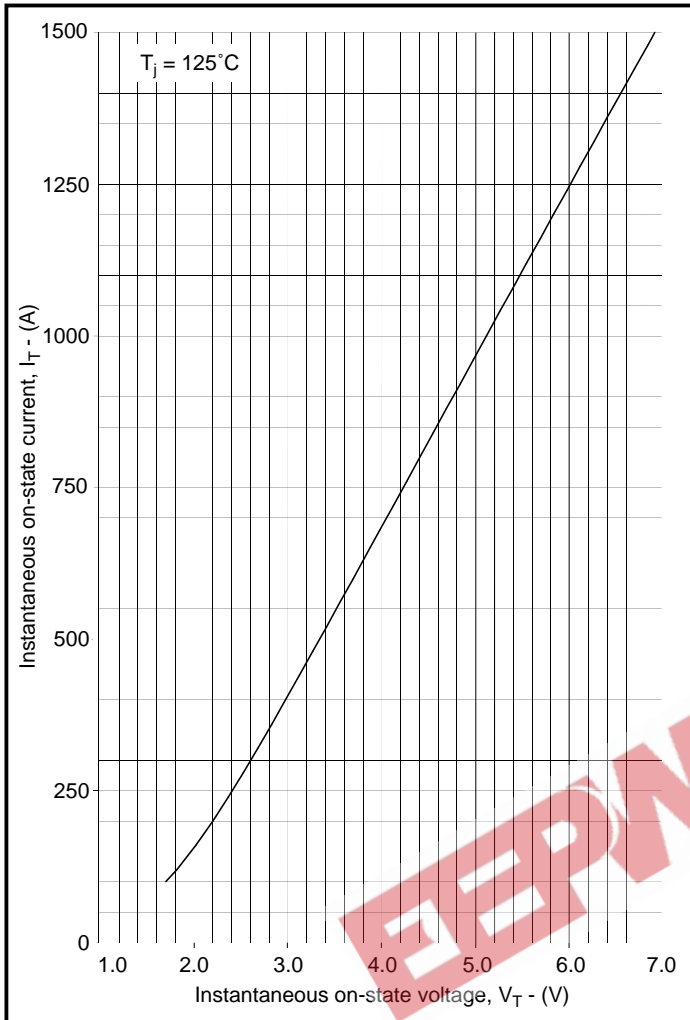
## DYNAMIC CHARACTERISTICS

Symbol	Parameter	Conditions	Min.	Max.	Units	
$I_{RRM}/I_{DRM}$	Peak reverse and off-state current	At $V_{RRM}/V_{DRM}$ , $T_{case} = 125^{\circ}C$	-	50	mA	
$dV/dt$	Maximum linear rate of rise of off-state voltage	To 67% $V_{DRM}$ , $T_j = 125^{\circ}C$ .	-	1000	V/ $\mu$ s	
$di/dt$	Rate of rise of on-state current	From 67% $V_{DRM}$ to 1000A, Gate source 10V, 5 $\Omega$ , $t_r \leq 0.5\mu$ s, $T_j = 125^{\circ}C$ .	Repetitive 50Hz	-	50	A/ $\mu$ s
			Non-repetitive	-	100	A/ $\mu$ s
$V_{T(To)}$	Threshold voltage	At $T_{vj} = 125^{\circ}C$	-	1.6	V	
$r_T$	On-state slope resistance	At $T_{vj} = 125^{\circ}C$	-	3.5	m $\Omega$	
$t_{gd}$	Delay time	$V_D = 67\% V_{DRM}$ , Gate source 20V, 10 $\Omega$ , Rise time 0.5 $\mu$ s, $T_j = 25^{\circ}C$	-	3.3	$\mu$ s	
$I_L$	Latching current	$T_j = 25^{\circ}C$ , $V_D = 20V$ .	-	1	A	
$I_H$	Holding current	$T_j = 25^{\circ}C$ , $V_D = 5V$ , $I_T = 5A$ , $I_{TM} = 500A$	30	120	mA	
$t_q$	Turn-off time	$I_T = 500A$ , $t_p = 1ms$ , $T_j = 125^{\circ}C$ , $V_{RM} = 100V$ , $dI_{RR}/dt = 10A/\mu$ s, $dV_{DR}/dt = 25V/\mu$ s to 3000V	500	1200	$\mu$ s	
$Q_S$	Stored charge - triangular approximation through $I_{RR}$ and 25% $I_{RR}$	$I_T = 320A$ , $-dI_T/dt = 6A/\mu$ s	600	1500	$\mu$ C	

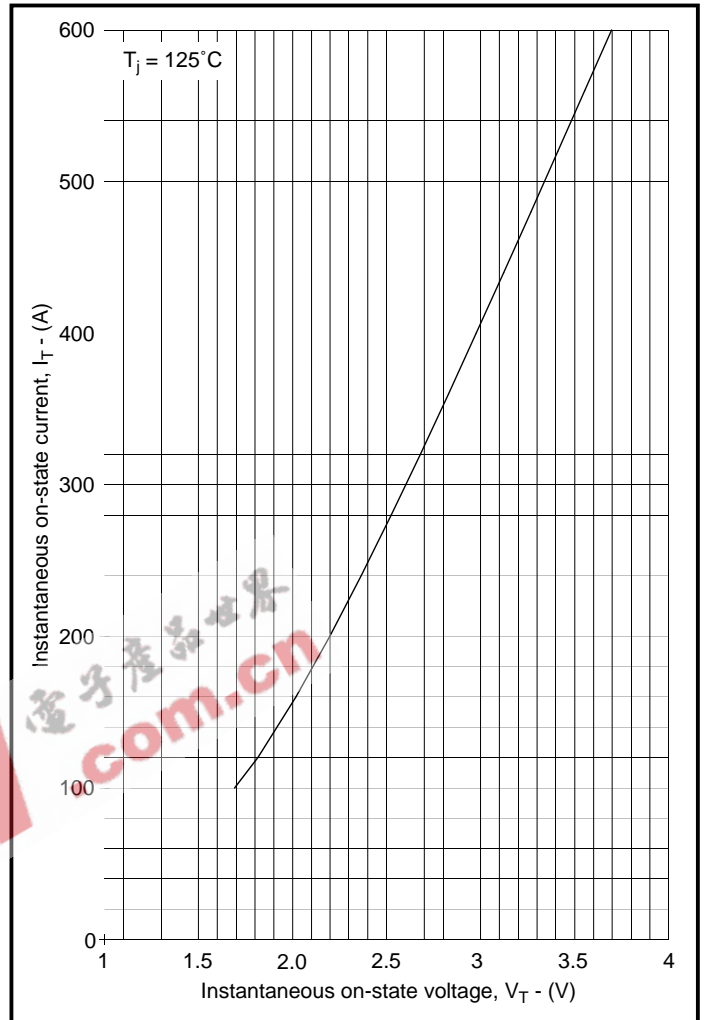
## GATE TRIGGER CHARACTERISTICS AND RATINGS

Symbol	Parameter	Conditions	Typ.	Max.	Units
$V_{GT}$	Gate trigger voltage	$V_{DRM} = 5V$ , $T_{case} = 25^{\circ}C$	-	3.0	V
$I_{GT}$	Gate trigger current	$V_{DRM} = 5V$ , $T_{case} = 25^{\circ}C$	-	300	mA
$V_{GD}$	Gate non-trigger voltage	At $V_{DRM}$ , $T_{case} = 125^{\circ}C$	-	0.25	V
$V_{FGM}$	Peak forward gate voltage	Anode positive with respect to cathode	-	30	V
$V_{FGN}$	Peak forward gate voltage	Anode negative with respect to cathode	-	0.25	V
$V_{RGM}$	Peak reverse gate voltage		-	5	V
$I_{FGM}$	Peak forward gate current	Anode positive with respect to cathode	-	10	A
$P_{GM}$	Peak gate power	See Fig.8/9 Gate characteristics curves and table	-	100	W
$P_{G(AV)}$	Mean gate power		-	5	W

**CURVES**



**Fig.2 Maximum (limit) on-state characteristics**



**Fig.3 Maximum (limit) on-state characteristics**

$V_{TM}$  Equation:-

$$V_{TM} = A + B \ln(I_T) + C \cdot I_T + D \cdot \sqrt{I_T}$$

Where

$$A = -0.759775$$

$$B = 0.639225$$

$$C = 0.004376$$

$$D = -0.092153$$

these values are valid for  $T_j = 125^\circ\text{C}$  for  $I_T$  100A to 1500A

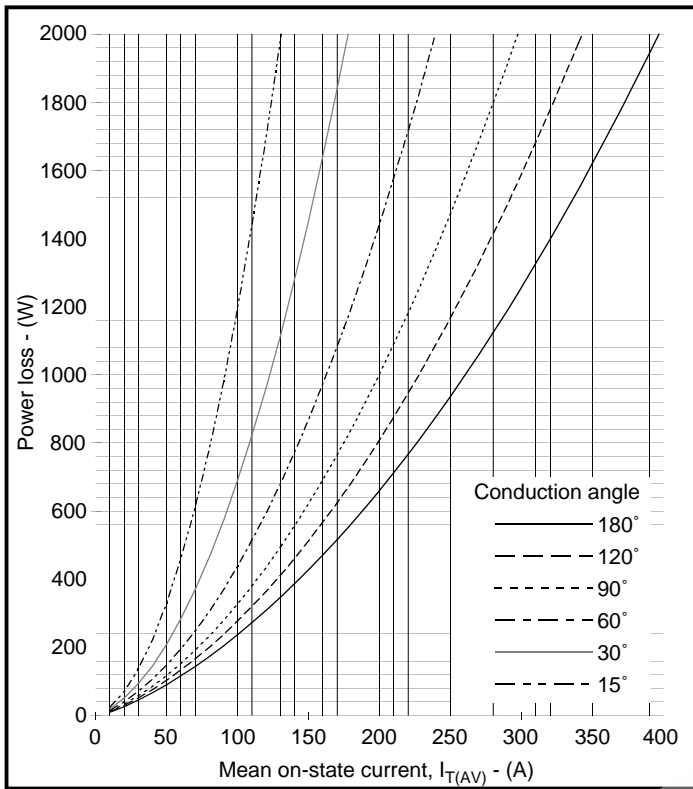


Fig.4 Sine wave power dissipation curves

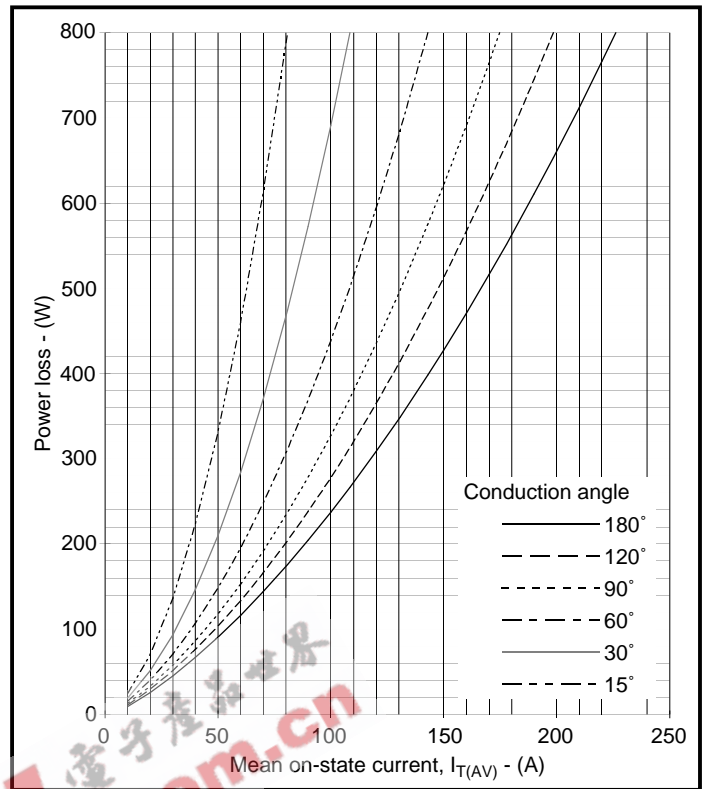


Fig.5 Sine wave power dissipation curves

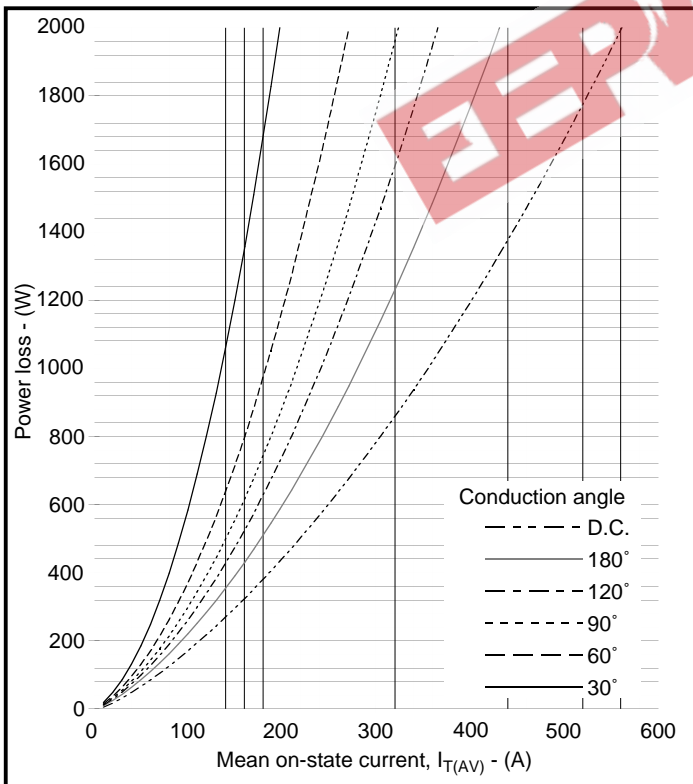


Fig.6 Square wave power dissipation curves

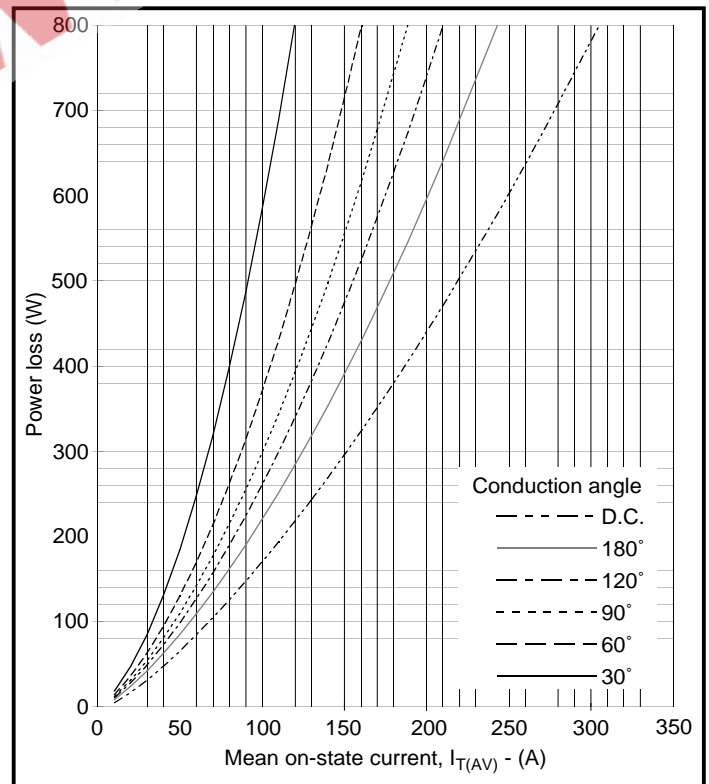
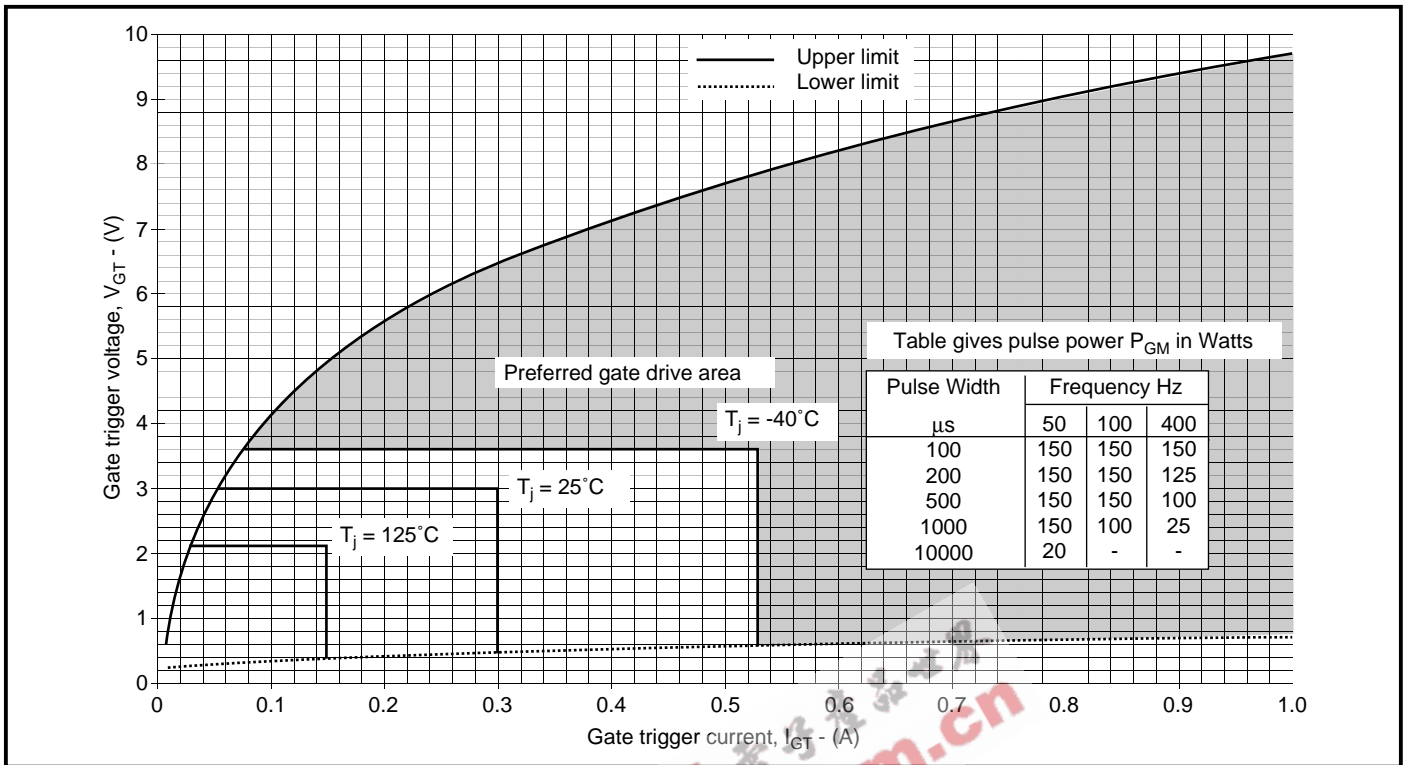
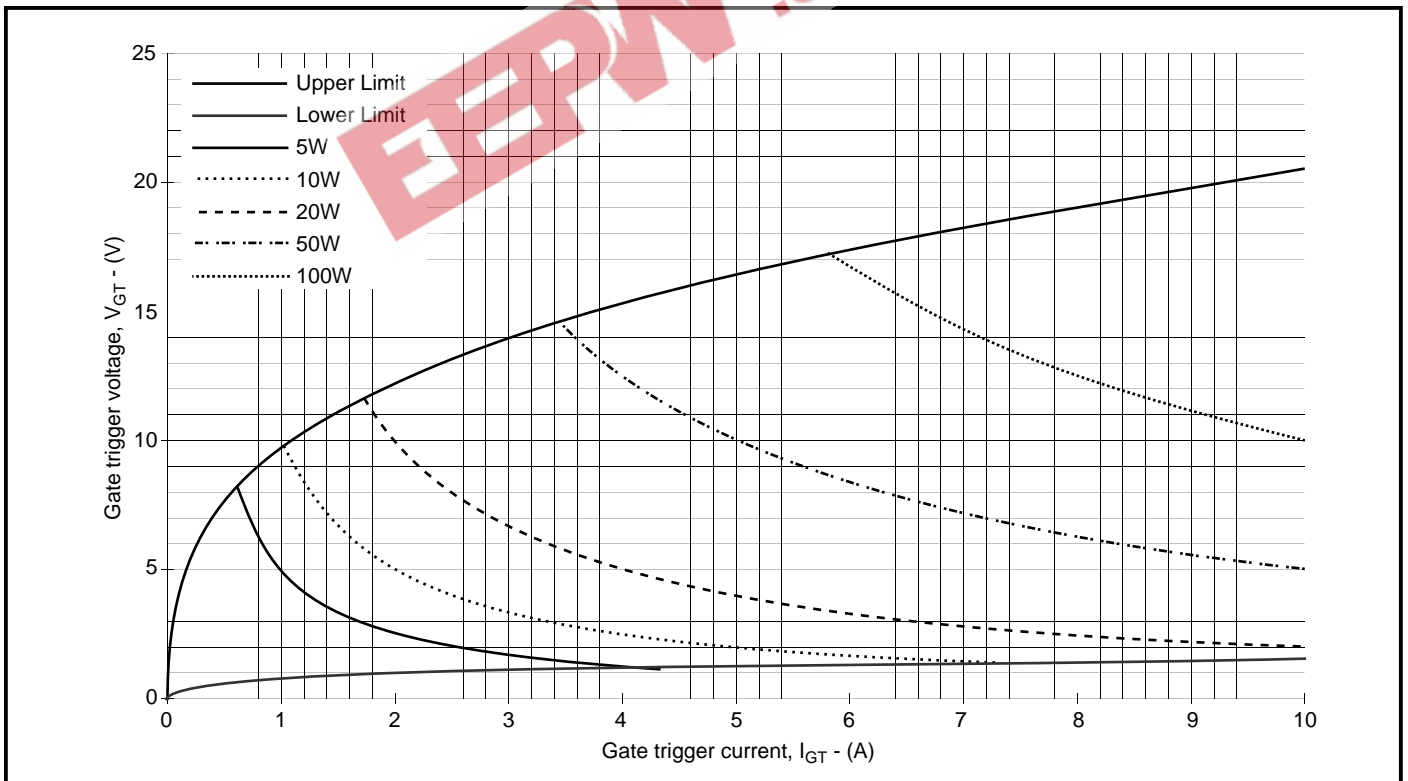


Fig.7 Square wave power dissipation curves



**Fig.8 Gate characteristics**



**Fig.9 Gate characteristics**

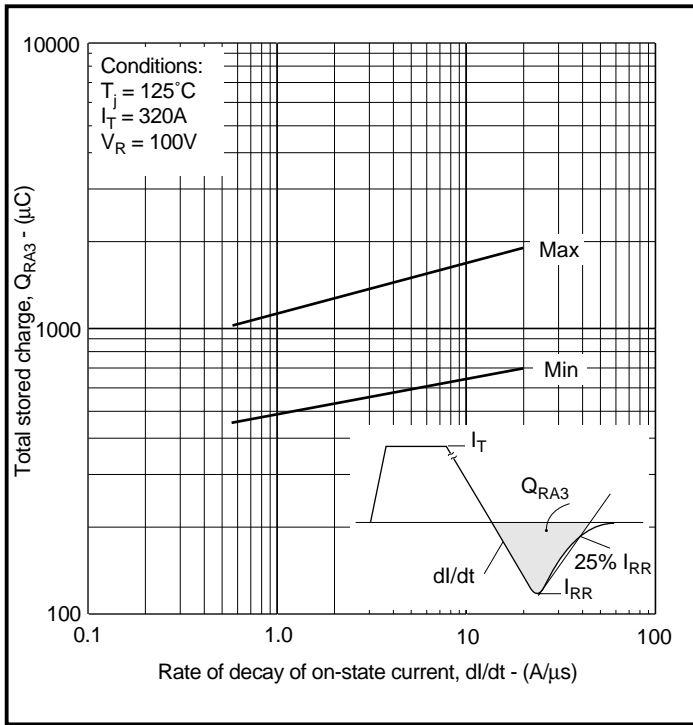


Fig.10 Stored charge

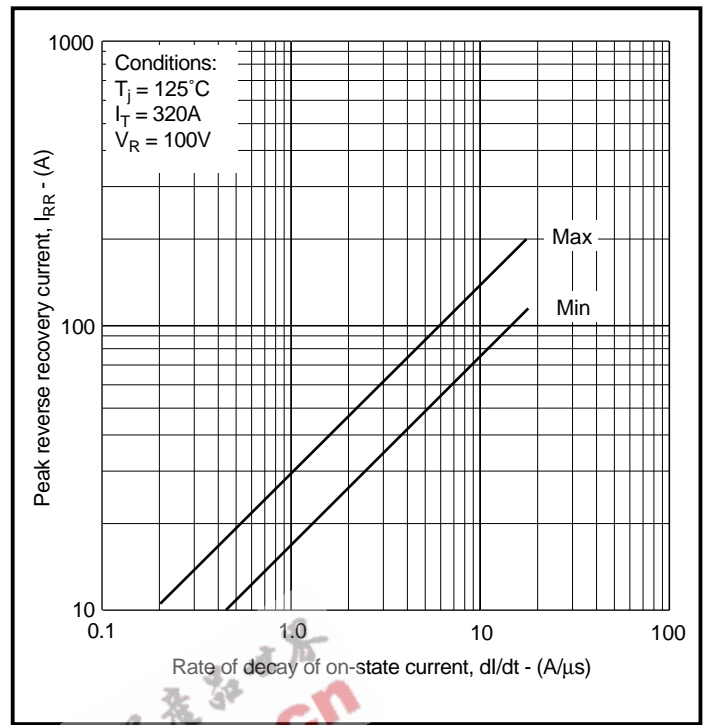


Fig.11 Reverse recovery current

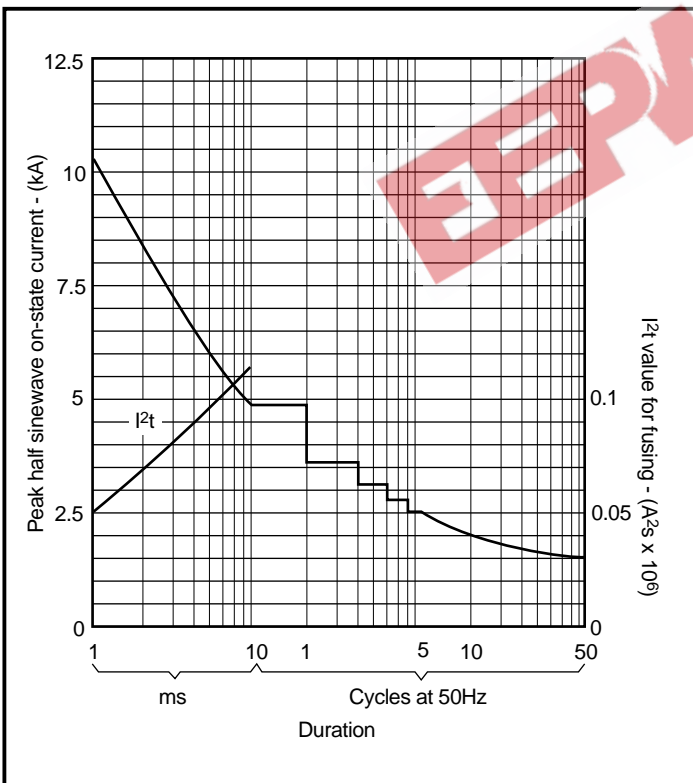


Fig.12 Surge (non-repetitive) on-state current vs time (with 50%  $V_{RRM}$  @  $T_{case} = 125^\circ\text{C}$ )

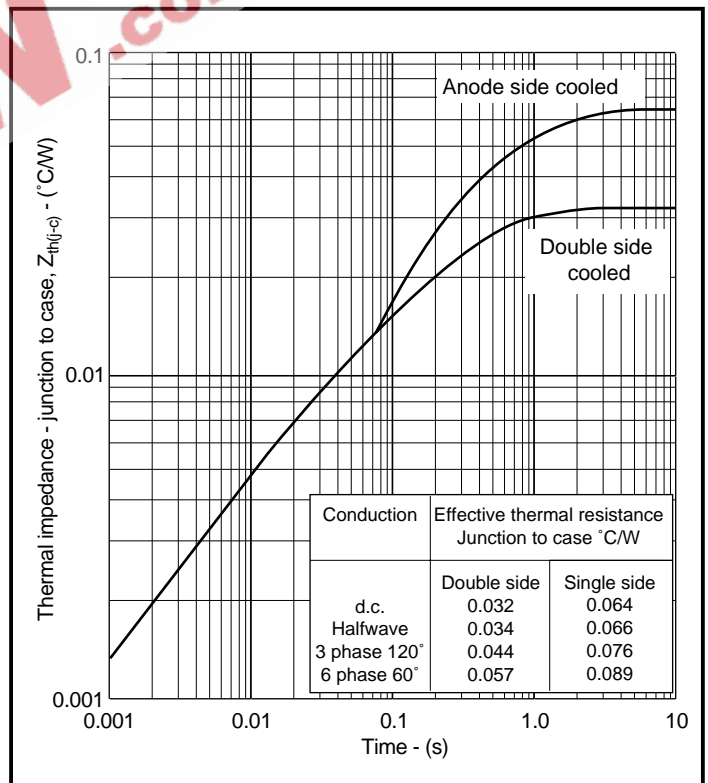
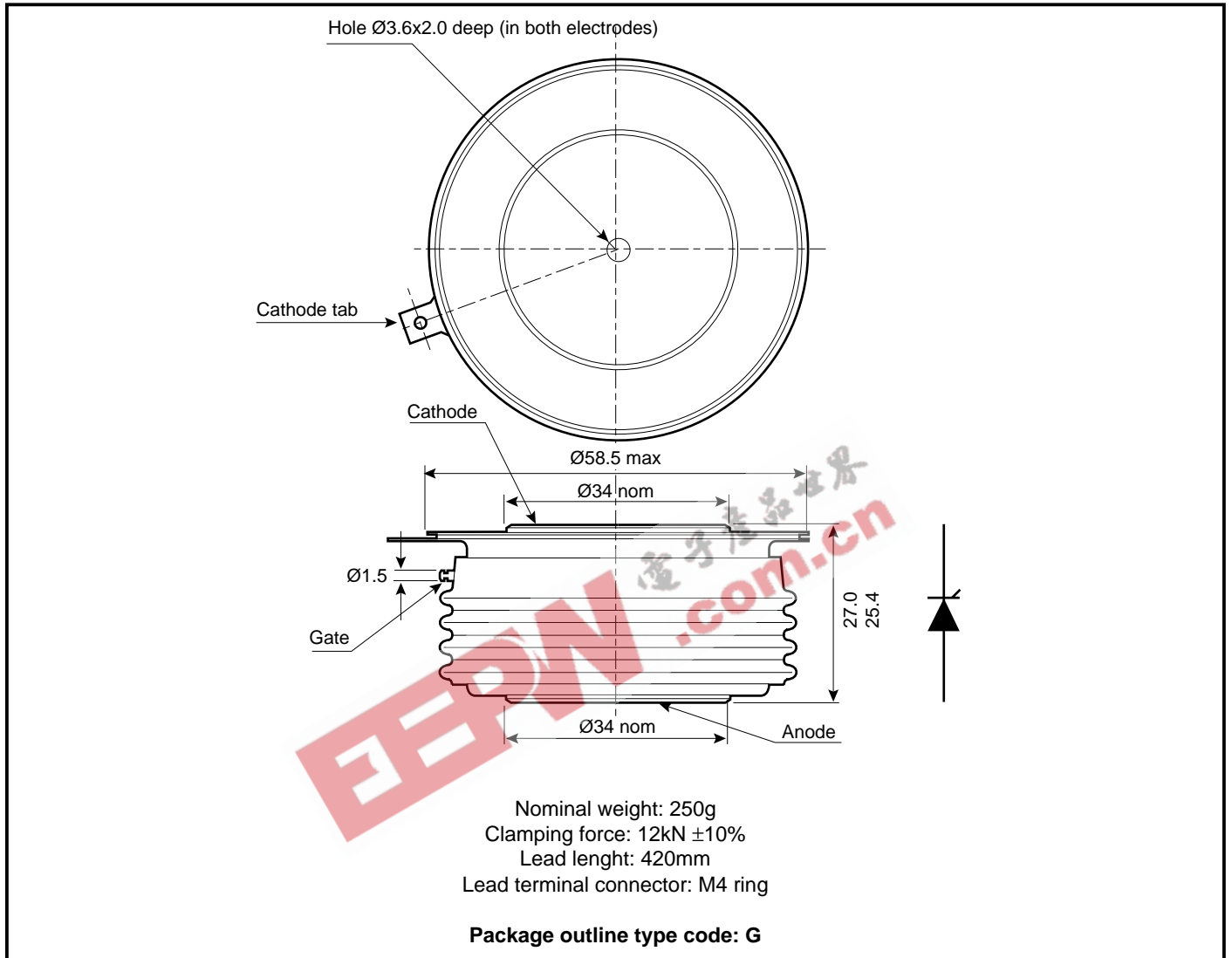


Fig.13 Maximum (limit) transient thermal impedance - junction to case



**PACKAGE DETAILS**

For further package information, please contact your nearest Customer Service Centre. All dimensions in mm, unless stated otherwise. DO NOT SCALE.



## POWER ASSEMBLY CAPABILITY

The Power Assembly group was set up to provide a support service for those customers requiring more than the basic semiconductor, and has developed a flexible range of heatsink / clamping systems in line with advances in device types and the voltage and current capability of our semiconductors.

We offer an extensive range of air and liquid cooled assemblies covering the full range of circuit designs in general use today. The Assembly group continues to offer high quality engineering support dedicated to designing new units to satisfy the growing needs of our customers.

Using the up to date CAD methods our team of design and applications engineers aim to provide the Power Assembly Complete solution (PACs).

## DEVICE CLAMPS

Disc devices require the correct clamping force to ensure their safe operation. The PACs range offers a varied selection of pre-loaded clamps to suit all of our manufactured devices. This include cube clamps for single side cooling of 'T' 22mm

Clamps are available for single or double side cooling, with high insulation versions for high voltage assemblies.

Please refer to our application note on device clamping, AN4839

## HEATSINKS

Power Assembly has its own proprietary range of extruded aluminium heatsinks. They have been designed to optimise the performance of our semiconductors. Data with respect to air natural, forced air and liquid cooling (with flow rates) is available on request.

For further information on device clamps, heatsinks and assemblies, please contact your nearest Sales Representative or Customer Services.



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